High Voltage FET-Input
OPERATIONAL AMPLIFIER

FEATURES

- WIDE-POWER SUPPLY RANGE: ±10V to ±45V
- HIGH SLEW RATE: 15V/µs
- LOW INPUT BIAS CURRENT: 10pA
- STANDARD-PINOUT TO-99, DIP, SO-8 PowerPAD™, AND SO-8 SURFACE-MOUNT PACKAGES

APPLICATIONS

- TEST EQUIPMENT
- HIGH-VOLTAGE REGULATORS
- POWER AMPLIFIERS
- DATA ACQUISITION
- SIGNAL CONDITIONING
- AUDIO
- PIEZO DRIVERS

DESCRIPTION

The OPA445 is a monolithic operational amplifier capable of operation from power supplies up to ±45V and output currents of 15mA. It is useful in a wide variety of applications requiring high output voltage or large common-mode voltage swings.

The OPA445’s high slew rate provides wide power-bandwidth response, which is often required for high-voltage applications. FET input circuitry allows the use of high-impedance feedback networks, thus minimizing their output loading effects. Laser trimming of the input circuitry yields low input offset voltage and drift.

The OPA445 is available in standard pinout TO-99, DIP-8, and SO-8 surface-mount packages as well as an SO-8 PowerPAD package for reducing junction temperature. It is fully specified from −25°C to +85°C and operates from −55°C to +125°C. A SPICE macromodel is available for design analysis (from www.ti.com).
ABSOLUTE MAXIMUM RATINGS(1)

<table>
<thead>
<tr>
<th>Specification</th>
<th>Rating</th>
</tr>
</thead>
<tbody>
<tr>
<td>Power Supply</td>
<td>±50V</td>
</tr>
<tr>
<td>Differential Input Voltage</td>
<td>±80V</td>
</tr>
<tr>
<td>Input Voltage Range</td>
<td></td>
</tr>
<tr>
<td>Storage Temperature Range: M</td>
<td>−65°C to +150°C</td>
</tr>
<tr>
<td></td>
<td>P, U, DDA −55°C to +125°C</td>
</tr>
<tr>
<td>Operating Temperature Range</td>
<td>−55°C to +125°C</td>
</tr>
<tr>
<td>Output Short-Circuit to Ground (T J &lt; +125°C)</td>
<td>Continuous</td>
</tr>
<tr>
<td>Junction Temperature: M</td>
<td>+175°C</td>
</tr>
<tr>
<td>Junction Temperature: P, U, DDA</td>
<td>+150°C</td>
</tr>
</tbody>
</table>

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not supported.

ORDERING INFORMATION(1)

<table>
<thead>
<tr>
<th>PRODUCT</th>
<th>PACKAGE-LEAD</th>
<th>PACKAGE DESIGNATOR</th>
<th>PACKAGE MARKING</th>
</tr>
</thead>
<tbody>
<tr>
<td>OPA445AP</td>
<td>DIP-8</td>
<td>P</td>
<td>OPA445AP</td>
</tr>
<tr>
<td>OPA445AU</td>
<td>SO-8 Surface-Mount</td>
<td>D</td>
<td>OPA445AU</td>
</tr>
<tr>
<td>OPA445ADDA</td>
<td>SO-8 PowerPAD</td>
<td>DDA</td>
<td>OPA445</td>
</tr>
<tr>
<td>OPA445BM</td>
<td>TO-99 8-Pin</td>
<td>LMC</td>
<td>OPA445BM</td>
</tr>
</tbody>
</table>

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.
ELECTRICAL CHARACTERISTICS

Boldface limits apply over the specified temperature range, $T_A = -25^\circ C$ to $+85^\circ C$, $V_S = \pm 40V$.

At $T_A = +25^\circ C$, $V_S = \pm 40V$, and $R_L = 5k\Omega$, unless otherwise noted.

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>OPA445BM</th>
<th>OPA445AP, AU, ADDA</th>
</tr>
</thead>
<tbody>
<tr>
<td>OFFSET VOLTAGE</td>
<td>$V_{OS}$, $V_{OS/dT}$</td>
<td>$V_{CM} = 0$, $I_O = 0$</td>
<td>$\pm 1$</td>
</tr>
<tr>
<td>vs Temperature</td>
<td>$V_{OS/dT}$</td>
<td>$T_A = -25^\circ C$ to $+85^\circ C$</td>
<td>$\pm 10$</td>
</tr>
<tr>
<td>vs Power Supply</td>
<td>PSRR</td>
<td>$V_S = \pm 10V$ to $\pm 45V$</td>
<td>4</td>
</tr>
</tbody>
</table>

| INPUT BIAS CURRENT(1) | $I_B$, $I_{OS}$ | $V_{CM} = 0V$ | $\pm 10$ | $\pm 50$ | $\pm 100$ | $\pm 20$ | pA |
| Over Specified Temperature Range | $I_B$, $I_{OS}$ | $V_{CM} = 0V$ | $\pm 4$ | $\pm 20$ | $\pm 40$ | $\pm 10$ | nA |

| NOISE | | | 15 | $+$ | $+$ | nV/\sqrt{Hz} |
| Input Voltage Noise Density, $f = 1kHz$ | $e_n$ | | 6 | $+$ | $+$ | IA/\sqrt{Hz} |
| Current Noise Density, $f = 1kHz$ | $i_n$ | | | | | |

| INPUT VOLTAGE RANGE | $V_{CM}$, $V_{OS}$ | $V_S = \pm 40V$ | $\pm 1$ | $\pm 3$ | $\pm 1.5$ | $\pm 5$ | V |
| Common-Mode Voltage Range | $V_{CM}$, $V_{OS}$ | $V_S = \pm 35V$ to $+35V$ | (V−) + 5 | (V+) − 5 | $+$ | $+$ | dB |
| Common-Mode Rejection | CMRR | $V_{CM} = -35V$ to $+35V$ | 80 | 95 | $+$ | $+$ | dB |
| Over Specified Temperature Range | CMRR | $V_{CM} = -35V$ to $+35V$ | 80 | | | |

| INPUT IMPEDANCE | Differential | $10^{13} \, | | | | | | dB |
| Common-Mode | $10^{12} \, | | | | | | dB |

| OPEN-LOOP GAIN, DC | $A_{OL}$ | $V_O = \pm 35V$ to $+35V$ | 100 | 110 | $+$ | $+$ | dB |
| Over Specified Temperature Range | $A_{OL}$ | $V_O = \pm 35V$ to $+35V$ | 97 | | $+$ | |

| FREQUENCY RESPONSE | Gain Bandwidth Product | GBW | 2 | $+$ | $+$ | MHz |
| Slow Rate | SR | $V_O = 70V_{PP}$ | 15 | $+$ | $+$ | V/\mu s |
| Full Power Bandwidth | | | | | | |
| Rise Time | | $V_O = 70V_{PP}$ | 70 | $+$ | $+$ | kHz |
| Overshoot | | $V_O = \pm 1V$ to $\pm 200mV$ | 100 | | $+$ | |
| Total Harmonic Distortion + Noise | THD+N | $f = 1kHz$, $V_O = 3.5V_{rms}$, $G = 1$ | 0.00002 | | $+$ | |
| | | $f = 1kHz$, $V_O = 10V_{rms}$, $G = 1$ | 0.00008 | | $+$ | |

| OUTPUT | Voltage Output | $V_O$ | (V−) + 5 | (V+) − 5 | $+$ | $+$ | V |
| Over Specified Temperature Range | Current Output | $I_O$ | $V_O = \pm 28V$ | $\pm 15$ | | $+$ | mA |
| Output Resistance, Open Loop | $R_O$ | $dc$ | 220 | $+$ | | $\Omega$ |
| Short Circuit Current | $I_{SC}$ | | $\pm 26$ | $+$ | | mA |
| Capacitive Load Drive | $C_{LOAD}$ | | | | | |

| POWER SUPPLY | Specified Operating Range | $V_S$ | $\pm 10$ | $\pm 40$ | $\pm 4.2$ | $\pm 4.7$ | V |
| Operating Voltage Range | $I_O$ | $I_O = 0$ | | | | | mA |

| TEMPERATURE RANGE | Specification Range | $-25$ | $+85$ | $-$ | $+$ | $^\circ C$ |
| Operating Range | $-55$ | $+125$ | $-$ | $+$ | $^\circ C$ |
| Storage Range | $-65$ | $+125$ | $-$ | $+$ | $^\circ C$ |
| Thermal Resistance, Junction-to-Ambient | $\rho_{JA}$ | 200 | | | | $^\circ C/W$ |
| TO-99 | DIP-8 | 100 | | | $^\circ C/W$ |
| SO-8 Surface-Mount | SO-8 PowerPAD(3) | 150 | | | $^\circ C/W$ |
| SO-8 PowerPAD(3) | | 52 | | | $^\circ C/W$ |
| Thermal Resistance, Junction-to-Case | $\rho_{JC}$ | 10 | | | $^\circ C/W$ |

NOTE: * Specifications same as OPA445BM.
(1) High-speed test at $T_J = +25^\circ C$.
(2) See Small-Signal Overshoot vs Load Capacitance in the Typical Characteristics section.
(3) Test board 1in x 0.5in heat-spreader, 1oz copper.
TYPICAL CHARACTERISTICS

At $T_A = +25 \, ^\circ\text{C}$ and $V_S = \pm 40\text{V}$, unless otherwise noted.
TYPICAL CHARACTERISTICS (continued)

At $T_A = +25^\circ C$ and $V_S = \pm 40V$, unless otherwise noted.
TYPICAL CHARACTERISTICS (continued)

At $T_A = +25^\circ C$ and $V_S = \pm 40V$, unless otherwise noted.

**OUTPUT VOLTAGE SWING vs OUTPUT CURRENT**

**SUPPLY CURRENT vs TEMPERATURE**

**OUTPUT VOLTAGE SWING vs TEMPERATURE**

**OUTPUT CURRENT vs TEMPERATURE**

**OFFSET VOLTAGE PRODUCTION DISTRIBUTION**

**OFFSET VOLTAGE DRIFT PRODUCTION DISTRIBUTION**

Typical production distribution of packaged units.
TYPICAL CHARACTERISTICS (continued)

At $T_A = +25^\circ C$ and $V_S = \pm 40V$, unless otherwise noted.

**MAXIMUM POWER DISSIPATION vs TEMPERATURE**

![Diagram showing maximum power dissipation vs temperature for different packages](image)

**MAXIMUM OUTPUT VOLTAGE SWING vs FREQUENCY**

![Diagram showing maximum output voltage swing vs frequency](image)

**SMALL-SIGNAL STEP RESPONSE**

$G = 1, C_L = 100pF$

![Diagram showing small-signal step response](image)

**LARGE-SIGNAL STEP RESPONSE**

$G = 1, C_L = 100pF$

![Diagram showing large-signal step response](image)
APPLICATIONS

Figure 1 shows the OPA445 connected as a basic noninverting amplifier. The OPA445 can be used in virtually any op amp configuration.

Power-supply terminals should be bypassed with 0.1 µF capacitors, or greater, near the power supply pins. Be sure that the capacitors are appropriately rated for the power-supply voltage used.

\[ G = 1 + \frac{R_2}{R_1} \]

\[ Z_L \]

\[ V_O \]

\[ V_{IN} \]

\[ V_{+} \]

\[ V_{-} \]

\[ 0.1 \mu F \]

\[ 0.1 \mu F \]

Figure 1. The OPA445 Configured as a Noninverting Amplifier

POWER SUPPLIES

The OPA445 may be operated from power supplies up to ±45V or a total of 90V with excellent performance. Most behavior remains unchanged throughout the full operating voltage range. Parameters which vary significantly with operating voltage are shown in the Typical Characteristics.

Some applications do not require equal positive and negative output voltage swing. Power-supply voltages do not need to be equal. The OPA445 can operate with as little as 20V between the supplies and with up to 90V between the supplies. For example, the positive supply could be set to 80V with the negative supply at −10V, or vice-versa.

INPUT PROTECTION

The inputs of conventional FET-input op amps should be protected against destructive currents that can flow when input FET gate-to-substrate isolation diodes are forward-biased. This can occur if the input voltage exceeds the power supplies or there is an input voltage with \( V_S = 0V \). Protection is easily accomplished with a resistor in series with the input. Care should be taken because the resistance in series with the input capacitance may affect stability. Many input signals are inherently current-limited; therefore, a limiting resistor may not be required.

OFFSET VOLTAGE TRIM

The OPA445 provides offset voltage trim connections on pins 1 and 5. Offset voltage can be adjusted by connecting a potentiometer as shown in Figure 2. This adjustment should be used only to null the offset of the op amp, not to adjust system offset or offset produced by the signal source. Nulling system offset could degrade the offset voltage drift behavior of the op amp. While it is not possible to predict the exact change in drift, the effect is usually small.

\[ 10mV \text{ Typical Trim Range} \]

\[ (10k\Omega \text{ to } 1M\Omega \text{ recommended}) \]

Figure 2. Offset Voltage Trim
CAPACITIVE LOADS

The dynamic characteristics of the OPA445 have been optimized for commonly encountered gains, loads, and operating conditions. The combination of low closed-loop gain and capacitive load will decrease the phase margin and may lead to gain peaking or oscillations. Figure 3 shows a circuit which preserves phase margin with capacitive load. The circuit does not suffer a voltage drop due to load current; however, input impedance is reduced at high frequencies. Consult Application Bulletin SBOA015, available for download at www.ti.com, for details of analysis techniques and application circuits.

\[ R_C = R_2 \times 2C_L \times 10^{-10} - \frac{1}{1 + R_2/R_1} \]
\[ C_C = \frac{C_L \times 10^3}{R_C} \]

NOTE: Design equations and component values are approximate. User adjustment is required for optimum performance.

Figure 3. Driving Large Capacitive Loads

INCREASING OUTPUT CURRENT

In those applications where the 15mA of output current is not sufficient to drive the required load, output current can be increased by connecting two or more OPA445s in parallel as shown in Figure 4. Amplifier A1 is the master amplifier and may be configured in virtually any op amp circuit. Amplifier A2, the slave, is configured as a unity gain buffer. Alternatively, external output transistors can be used to boost output current. The circuit in Figure 5 is capable of supplying output currents up to 1A.

\[ R_S(1) \]
\[ R_4 \]

NOTE: (1) Provides current limit for OPA445 and allows the amplifier to drive the load when the output is between +0.7V and −0.7V.

Figure 5. External Output Transistors Boost Output Current Up to 1 Amp

Figure 4. Parallel Amplifiers Increase Output Current Capability
SAFE OPERATING AREA

Stress on the output transistors is determined both by the output current and by the output voltage across the conducting output transistors, $V_S - V_O$. The power dissipated by the output transistor is equal to the product of the output current and the voltage across the conducting transistor, $V_S - V_O$. The Safe Operating Area (SOA curve, Figure 6 through Figure 10) illustrates the permissible range of voltage and current. The curves shown represent devices soldered to a printed circuit board (PCB) with no heat sink. Increasing printed circuit trace area or the use of a heat sink (TO-99 package) can significantly reduce thermal resistance ($\theta$), resulting in increased output current for a given output voltage (see Figure 11, Figure 12, and the Heat Sink section).

The safe output current decreases as $V_S - V_O$ increases. Output short-circuits are a very demanding case for SOA. A short-circuit to ground forces the full power supply voltage ($V+$ or $V-$) across the conducting transistor and produces a typical output current of 25mA. With ±40V power supplies, this creates an internal dissipation of 1W. This exceeds the maximum rating and is not recommended. If operation in this region is unavoidable, a heat sink is required. For further insight on SOA, consult Application Bulletin SBOA022 (available for download at www.ti.com).

**Figure 6. DIP-8 Safe Operating Area**

**Figure 7. TO-99 Safe Operating Area**

**Figure 8. SO-8 (non PowerPAD) Safe Operating Area**

**Figure 9. SO-8 PowerPAD Safe Operating Area**
(no heat-spreader, no airflow)
POWER DISSIPATION

Power dissipation depends on power supply, signal, and load conditions. For dc signals, power dissipation is equal to the product of the output current times the voltage across the conducting output transistor, \( P_D = I_O (V_S - V_O) \).

Power dissipation can be minimized by using the lowest possible power-supply voltage necessary to assure the required output voltage swing.

For resistive loads, the maximum power dissipation occurs at a dc output voltage of one-half the power supply voltage. Dissipation with ac signals is lower. Application Bulletin SBOA022 explains how to calculate or measure dissipation with unusual loads or signals.

The OPA445 can supply output currents of 15mA and larger. This would present no problem for a standard op amp operating from ±15V supplies. With high supply voltages, however, internal power dissipation of the op amp can be quite large. Operation from a single power supply (or unbalanced power supplies) can produce even larger power dissipation since a large voltage is impressed across the conducting output transistor. Applications with large power dissipation may require a heat-sink.

HEAT SINKING

Power dissipated in the OPA445 will cause the junction temperature to rise. For reliable operation junction temperature should be limited to 125°C, maximum (150°C for TO-99 package). Some applications will require a heat-sink to assure that the maximum operating junction temperature is not exceeded. In addition, the junction temperature should be kept as low as possible for increased reliability. Junction temperature can be determined according to the following equation:

\[
T_J = T_A + P_D \theta_{JA}
\] (1)

Package thermal resistance, \( \theta_{JA} \), is affected by mounting techniques and environments. Poor air circulation and use of sockets can significantly increase thermal resistance. Best thermal performance is achieved by soldering the op amp into a circuit board with wide printed circuit traces to allow greater conduction through the op amp leads. Simple clip-on heat sinks (such as a Thermalloy 2257) can reduce the thermal resistance of the TO-99 metal package by as much as 50°C/W. The SO-8 PowerPAD package will provide lower thermal resistance, especially with a simple heat-spreader—even lower with a heat-sink. For additional information on determining heat-sink requirements, consult Application Bulletin SBOA021.
PowerPAD THERMALLY-ENHANCED PACKAGE

In addition to the SO-8, DIP-8, and TO-99 packages, the OPA445 also comes in an SO-8 PowerPAD. The SO-8 PowerPAD is a standard-size SO-8 package where the exposed leadframe on the bottom of the package can be soldered directly to the PCB to create an extremely low thermal resistance. This architecture enhances the OPA445’s power dissipation capability significantly and eliminates the use of bulky heatsinks and slugs traditionally used in thermal packages. This package can be easily mounted using standard PCB assembly techniques. NOTE: Since the SO-8 PowerPAD is pin-compatible with standard SO-8 packages, the OPA445 can directly replace operational amplifiers in existing sockets. Soldering the PowerPAD to the PCB is always required, even with applications that have low power dissipation. Soldering the device to the PCB provides the necessary thermal and mechanical connection between the leadframe die pad and the PCB.

The PowerPAD package is designed so that the leadframe die pad (or thermal pad) is exposed on the bottom of the IC; see Figure 13. This design provides an extremely low thermal resistance (\(\theta_{ic}\)) path between the die and the exterior of the package. The thermal pad on the bottom of the IC can then be soldered directly to the PCB, using the PCB as a heatsink. In addition, plated-through holes (vias) provide a low thermal resistance heat flow path to the back side of the PCB.

The PowerPAD package allows for both assembly and thermal management in one manufacturing operation. During the surface-mount solder operation (when the leads are being soldered), the thermal pad must be soldered to a copper area underneath the package. Through the use of thermal paths within this copper area, heat can be conducted away from the package into either a ground plane or other heat-dissipating device. Soldering the PowerPAD to the PCB is always required, even with applications that have low power dissipation. Follow these steps:

1. The PowerPAD must be connected to the most negative supply voltage on the device, \(V_{-}\).
2. Prepare the PCB with a top-side etch pattern. There should be etching for the leads as well as etch for the thermal pad.
3. Place recommended holes in the area of the thermal pad. Recommended thermal land size and thermal via patterns for the SO-8 DDA package is shown in Figure 14. These holes should be 13 mils in diameter. Keep them small, so that solder wicking through the holes is not a problem during reflow. The minimum recommended number of holes for the SO-8 PowerPAD package is five.
4. Additional vias may be placed anywhere along the thermal plane outside of the thermal pad area. These vias help dissipate the heat generated by the OPA445 IC. These additional vias may be larger than the 13-mil diameter vias directly under the thermal pad. They can be larger because they are not in the thermal pad area to be soldered; thus, wicking is not a problem.
5. Connect all holes to the internal power plane of the correct voltage potential (\(V_{-}\)).
6. When connecting these holes to the plane, do not use the typical web or spoke via connection methodology. Web connections have a high thermal resistance connection that is useful for slowing the heat transfer during soldering operations, making the soldering of vias that have plane connections easier. In this application, however, low thermal resistance is desired for the most efficient heat transfer. Therefore, the holes under the OPA445 PowerPAD package should make the connections to the internal plane with a complete connection around the entire circumference of the plated-through hole.
7. The top-side solder mask should leave the terminals of the package and the thermal pad area exposed. The bottom-side solder mask should cover the holes of the thermal pad area. This masking prevents solder from being pulled away from the thermal pad area during the reflow process.
8. Apply solder paste to the exposed thermal pad area and all of the IC terminals.

Figure 13. Section View of a PowerPAD Package

GENERAL PowerPAD LAYOUT GUIDELINES

The OPA445 is available in a thermally-enhanced PowerPAD package. This package is constructed using a downset leadframe upon which the die is mounted. This arrangement results in the lead frame being exposed as a thermal pad on the underside of the package. This thermal pad has direct thermal contact with the die; thus, excellent thermal performance is achieved by providing a good thermal path away from the thermal pad.
9. With these preparatory steps in place, the PowerPAD IC is simply placed in position and run through the solder reflow operation as any standard surfacemount component. This preparation results in a properly installed part.

For detailed information on the PowerPAD package, including thermal modeling considerations and repair procedures, see technical brief SLMA002 PowerPAD Thermally-Enhanced Package available for download at www.ti.com.

Figure 14. 8-Pin PowerPAD PCB Etch and Via Pattern

TYPICAL APPLICATIONS

Figure 15. Voltage-to-Current Converter

Figure 16. Programmable Voltage Source

Figure 17. Bridge Circuit Doubles Voltage for Piezo Crystals

NOTE: (1) For transducers with large capacitance the stabilization technique described in Figure 6 may be necessary. Be certain that the Master amplifier is stable before stabilizing the Slave amplifier.
PACKAGING INFORMATION

<table>
<thead>
<tr>
<th>Orderable Device</th>
<th>Status (1)</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>Package Qty</th>
<th>Eco Plan (2)</th>
<th>Lead/Ball Finish</th>
<th>MSL Peak Temp (3)</th>
</tr>
</thead>
<tbody>
<tr>
<td>OPA445ADDA</td>
<td>ACTIVE</td>
<td>SO Power PAD</td>
<td>DDA</td>
<td>8</td>
<td>100</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>Level-2-260C-1 YEAR</td>
</tr>
<tr>
<td>OPA445ADDAG4</td>
<td>ACTIVE</td>
<td>SO Power PAD</td>
<td>DDA</td>
<td>8</td>
<td>100</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>Level-2-260C-1 YEAR</td>
</tr>
<tr>
<td>OPA445ADDAR</td>
<td>ACTIVE</td>
<td>SO Power PAD</td>
<td>DDA</td>
<td>8</td>
<td>2500</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>Level-2-260C-1 YEAR</td>
</tr>
<tr>
<td>OPA445ADDARG4</td>
<td>ACTIVE</td>
<td>SO Power PAD</td>
<td>DDA</td>
<td>8</td>
<td>2500</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>Level-2-260C-1 YEAR</td>
</tr>
<tr>
<td>OPA445AP</td>
<td>ACTIVE</td>
<td>PDIP</td>
<td>P</td>
<td>8</td>
<td>50</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>N / A for Pkg Type</td>
</tr>
<tr>
<td>OPA445APG4</td>
<td>ACTIVE</td>
<td>PDIP</td>
<td>P</td>
<td>8</td>
<td>50</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>N / A for Pkg Type</td>
</tr>
<tr>
<td>OPA445AU</td>
<td>ACTIVE</td>
<td>SOIC</td>
<td>D</td>
<td>8</td>
<td>100</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>Level-3-260C-168 HR</td>
</tr>
<tr>
<td>OPA445AU/2K5</td>
<td>ACTIVE</td>
<td>SOIC</td>
<td>D</td>
<td>8</td>
<td>2500</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>Level-3-260C-168 HR</td>
</tr>
<tr>
<td>OPA445AU/2K5E4</td>
<td>ACTIVE</td>
<td>SOIC</td>
<td>D</td>
<td>8</td>
<td>2500</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>Level-3-260C-168 HR</td>
</tr>
<tr>
<td>OPA445AUG4</td>
<td>ACTIVE</td>
<td>SOIC</td>
<td>D</td>
<td>8</td>
<td>100</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>CU NIPDAU</td>
<td>Level-3-260C-168 HR</td>
</tr>
<tr>
<td>OPA445BM</td>
<td>NRND</td>
<td>TO-99</td>
<td>LMC</td>
<td>8</td>
<td>20</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>AU</td>
<td>N / A for Pkg Type</td>
</tr>
</tbody>
</table>

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBsolete: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI’s terms “Lead-Free” or “Pb-Free” mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines “Green” to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI’s knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on
incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI’s liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.
TAPE AND REEL INFORMATION

### TAPE DIMENSIONS

- **A0**: Dimension designed to accommodate the component width
- **B0**: Dimension designed to accommodate the component length
- **K0**: Dimension designed to accommodate the component thickness
- **W**: Overall width of the carrier tape
- **P1**: Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

- **Q1**: Pocket Quadrants
- **Q2**: Sprocket Holes
- **Q3**: User Direction of Feed

*All dimensions are nominal.*

<table>
<thead>
<tr>
<th>Device</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>SPQ</th>
<th>Reel Diameter (mm)</th>
<th>Reel Width W1 (mm)</th>
<th>A0 (mm)</th>
<th>B0 (mm)</th>
<th>K0 (mm)</th>
<th>P1 (mm)</th>
<th>W (mm)</th>
<th>Pin1 Quadrant</th>
</tr>
</thead>
<tbody>
<tr>
<td>OPA445ADDAR</td>
<td>SO Power PAD</td>
<td>DDA</td>
<td>8</td>
<td>2500</td>
<td>330.0</td>
<td>12.4</td>
<td>6.4</td>
<td>5.2</td>
<td>2.1</td>
<td>8.0</td>
<td>12.0</td>
<td>Q1</td>
</tr>
<tr>
<td>OPA445AU/2K5</td>
<td>SOIC</td>
<td>D</td>
<td>8</td>
<td>2500</td>
<td>330.0</td>
<td>12.4</td>
<td>6.4</td>
<td>5.2</td>
<td>2.1</td>
<td>8.0</td>
<td>12.0</td>
<td>Q1</td>
</tr>
</tbody>
</table>
### TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal*

<table>
<thead>
<tr>
<th>Device</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>SPQ</th>
<th>Length (mm)</th>
<th>Width (mm)</th>
<th>Height (mm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>OPA445ADDAR</td>
<td>SO PowerPAD</td>
<td>DDA</td>
<td>8</td>
<td>2500</td>
<td>346.0</td>
<td>346.0</td>
<td>29.0</td>
</tr>
<tr>
<td>OPA445AU/2K5</td>
<td>SOIC</td>
<td>D</td>
<td>8</td>
<td>2500</td>
<td>346.0</td>
<td>346.0</td>
<td>29.0</td>
</tr>
</tbody>
</table>
D (R−PDSO−G8)  PLASTIC SMALL−OUTLINE PACKAGE

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
   ▲ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .005 (0.15) per end.
   ▲ Body width does not include interlead flash. Interlead flash shall not exceed .017 (0.43) per side.
E. Reference JEDEC MS−012 variation AA.

www.ti.com
DDA (R-PDSO-G8)  PowerPAD™ PLASTIC SMALL-OUTLINE PACKAGE

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0.15.
D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com <http://www.ti.com>.

PowerPAD is a trademark of Texas Instruments.
THERMAL INFORMATION

This PowerPAD™ package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.

NOTE: All linear dimensions are in millimeters.
MECHANICAL DATA

P (R-PDIP-T8)
PLASTIC DUAL-IN-LINE

NOTES:  
A. All linear dimensions are in inches (millimeters).  
B. This drawing is subject to change without notice.  
C. Falls within JEDEC MS-001

For the latest package information, go to http://www.ti.com/sc/docs/package/pkg_info.htm
MECHANICAL DATA

LMC (O-MBCY-W8) METAL CYLINDRICAL PACKAGE

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Leads in true position within 0.010 (0,25) R @ MMC at seating plane.
D. Pin numbers shown for reference only. Numbers may not be marked on package.
E. Fails within JEDEC MO-002/10-99.
**IMPORTANT NOTICE**

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI’s terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to test the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as “Military-Grade” or “Enhanced Plastic.” Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

<table>
<thead>
<tr>
<th>Products</th>
<th>Applications</th>
</tr>
</thead>
<tbody>
<tr>
<td>Amplifiers</td>
<td>Audio</td>
</tr>
<tr>
<td>Data Converters</td>
<td>Automotive</td>
</tr>
<tr>
<td>DSP</td>
<td>Broadband</td>
</tr>
<tr>
<td>Clocks and Timers</td>
<td>Digital Control</td>
</tr>
<tr>
<td>Interface</td>
<td>Medical</td>
</tr>
<tr>
<td>Logic</td>
<td>Military</td>
</tr>
<tr>
<td>Power Mgmt</td>
<td>Optical Networking</td>
</tr>
<tr>
<td>Microcontrollers</td>
<td>Security</td>
</tr>
<tr>
<td>RFID</td>
<td>Telephone</td>
</tr>
<tr>
<td>RF/I and ZigBee® Solutions</td>
<td>Video &amp; Imaging</td>
</tr>
<tr>
<td></td>
<td>Wireless</td>
</tr>
</tbody>
</table>

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2008, Texas Instruments Incorporated